

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





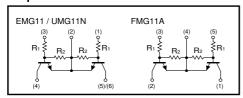


Emitter common (dual digital transistors) EMG11 / UMG11N / FMG11A

Features

1) Two DTA123Js chips in a EMT or UMT or SMT package.

Equivalent circuit



Package, marking, and packaging specifications

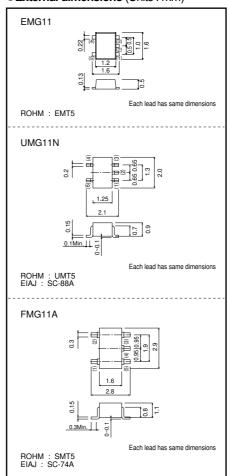
Туре	EMG11	UMG11N	FMG11A
Package	EMT5	UMT5	SMT5
Marking	G11	G11	G11
Code	T2R	TR	T148
Basic ordering unit (pieces)	8000	3000	3000

◆Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit	
Supply voltage	Vcc	50	V	
Input voltage	VIN	12	V	
	VIN	5		
Output current	lo	100	mA	
Power dissipation	Pd	150(TOTAL)	mW *1	
		300(TOTAL)	*2	
Storage temperature	Tstg	-50~+150	°C	

^{*1 120}mW per element must not be exceeded

●External dimensions (Units: mm)



●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input voltage	V _I (off)	-	-	0.5	V	Vcc=5V, Io=100μA
	VI (on)	1.1	_	-		Vo=0.3V, Io=5mA
Output voltage	Vo (on)	-	0.1	0.3	V	lo=5mA, li=0.25mA
Input current	lı .	-	-	3.6	mA	V⊫5V
Output current	IO (off)	-	-	0.5	μΑ	Vcc=50V, V⊫0V
DC current gain	Gı	80	-	-	-	Io=10mA, Vo=5V
Input resistance	R ₁	-	2.2	-	kΩ	-
Transition frequency	f⊤	-	250	-	MHz	VcE=10V, IE=-5mA, f=100MHz
Resistance ratio	B ₂ /B ₁	17	21	26	_	_

^{*}Transition frequency of the device.